## NSN 5961-01-382-7610

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| Internal Configuration:   |
|---|
| Junction contact  |
| Semiconductor Material:   |
| Silicon   |
| Voltage Rating In Volts Per Characteristic:   |
| 16.0 collector-to-emitter, substaining voltage, base open-circuited and 36.0 collector to base voltage/static/emitter open and 4.0 emitter to |
| base voltage, static, collector open  |
| Current Rating Per Characteristic:  |
| 400.00 milliamperes source cutoff current   |
| Power Rating Per Characteristic:  |
| 3.0 watts small-signal input power, common-collector absolute   |
| Maximum Operating Tempurature Per Measurement Point:  |
| 150.0 degrees celsius junction  |
| Special Features:   |
| Junction pattern arrangement: npn   |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
|   |
| Demilitarization:   |
| No  |
| Fiig:   |
| A110a0  |
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